

Multiple Choice Questions' Bank:

1. Electrical conductivity of insulators is in the range \_\_\_\_\_.

- (a)  $10^{-10}(\Omega\text{-mm})^{-1}$     (b)  $10^{-10}(\Omega\text{-cm})^{-1}$     (c)  $10^{-10}(\Omega\text{-m})^{-1}$     (d)  $10^{-8}(\Omega\text{-m})^{-1}$

2. Units for electric field strength

- (a) A/cm<sup>2</sup>    (b) mho/meter    (c) cm<sup>2</sup>/V.s    (d) V/cm

3. Energy band gap size for semiconductors is in the range \_\_\_\_\_ eV.

- (a) 1-2    (b) 2-3    (c) 3-4    (d) > 4

4. Energy band gap size for insulators is in the range \_\_\_\_\_ eV.

- (a) 1-2    (b) 2-3    (c) 3-4    (d) > 4

5. Flow of electrons is affected by the following

- (a) Thermal vibrations (b) Impurity atoms    (c) Crystal defects    (d) all

6. Not a super conductive metallic element

- (a) Fe    (b) Al    (c) Ti    (d) W

7. Fermi energy level for intrinsic semiconductors lies

- (a) At middle of the band gap    (b) Close to conduction band  
(c) Close to valence band    (d) None

8. Fermi energy level for *p*-type extrinsic semiconductors lies

- (a) At middle of the band gap    (b) Close to conduction band  
(c) Close to valence band    (d) None

9. Fermi energy level for *n*-type extrinsic semiconductors lies

- (a) At middle of the band gap    (b) Close to conduction band  
(c) Close to valence band    (d) None

10. Not an example for intrinsic semiconductor

- (a) Si    (b) Al    (c) Ge    (d) Sn

11. In intrinsic semiconductors, number of electrons \_\_\_\_\_ number of holes.

- (a) Equal      (b) Greater than      (c) Less than      (d) Can not define

12. In *n*-type semiconductors, number of holes \_\_\_\_\_ number of electrons.

- (a) Equal      (b) Greater than      (c) Less than      (d) Can not define

13. In *p*-type semiconductors, number of holes \_\_\_\_\_ number of electrons.

- (a) Equal      (b) Greater than      (c) Less than      (d) Twice

14. Mobility of holes is \_\_\_\_\_ mobility of electrons in intrinsic semiconductors.

- (a) Equal      (b) Greater than      (c) Less than      (d) Can not define

15. Fermi level for extrinsic semiconductor depends on

- (a) Donor element      (b) Impurity concentration      (c) Temperature      (d) All

16. Value of dielectric constant for a material \_\_\_\_\_.

- (a) Equal to 1      (b) Greater than 1      (c) Less than 1      (d) Zero.

17. High dielectric constant material is must for \_\_\_\_\_.

- (a) Insulation of wires      (b) Generators      (c) Switch bases      (d) Generators.

18. Dielectric constant for most polymers lies in the range of \_\_\_\_\_.

- (a) 1-3      (b) 2-5      (c) 4-7      (d) 6-10.

19. Example for piezo-electric material

- (a) Rochelle salt      (b) Lead zirconate      (c) Potassium niobate      (d) Barium Titanium oxide

20. Example for ferro-electric material

- (a) Potassium niobate      (b) Lead titanate      (c) Lead zirconate      (d) quartz

Answers:

1. a

- 2. c
- 3. b
- 4. c
- 5. d
- 6. b
- 7. c
- 8. b
- 9. b
- 10. a
- 11. c
- 12. d
- 13. a
- 14. d
- 15. d
- 16. a
- 17. a
- 18. c
- 19. b
- 20. b